



RF4E100AJTCR Information

Heisener.com

Part Number RF4E100AJTCR
Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description NCH 30V 10A MIDDLE POWER MOSFET

Package 8-PowerUDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RF4E100AJTCR Specifications

Manufacturer Part Number	RF4E100AJTCR
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerUDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V
Vgs(th) (Max) @ Id	1.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1460pF @ 15V
Vgs (Max)	±12V
FET Feature	-
Power Dissipation (Max)	2W (Tc)
Rds On (Max) @ Id, Vgs	12.4 mOhm @ 10A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	HUML2020L8
Package / Case	8-PowerUDFN
	Report errors?

RF4E100AJTCR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RF4E100AJTCR Payment Methods





















RF4E100AJTCR Shipping Methods













If you have any question about RF4E100AJTCR, please do not hesitate to contact us!

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